

### PNP -2.5A -80V Middle Power Transistor

Parameter	Value
$V_{CEO}$	-80V
I <sub>C</sub>	-2.5A

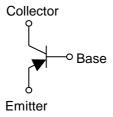
### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR544P
- 3) Low V<sub>CE(sat)</sub>

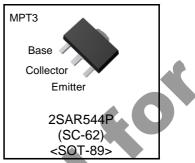
$$V_{CE(sat)} = -0.4V \text{ Max. } (I_C/I_B = -1A/-50\text{mA})$$

4) Lead Free/RoHS Compliant.

### •Inner circuit



### Outline



## Applications

Motor driver, LED driver Power supply

### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR544P	MPT3	4540	T100	180	12	1,000	MS

## ● Absolute maximum ratings (Ta = 25°C)

Parame	eter	Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	-80	V
Collector-emitter voltage		$V_{CEO}$	-80	V
Emitter-base voltage		V <sub>EBO</sub>	-6	V
Collector current	DC	I <sub>C</sub>	-2.5	А
	Pulsed	I <sub>CP</sub> *1	-5.0	А
Power dissipation	2SAR544P	$P_{D}$	0.5 <sup>*2</sup>	W
- wei dissipation	20/11/0441	י ט	2.0 *3	W
Junction temperature		$T_j$	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +150	°C

<sup>\*1</sup> Pw=10ms, single pulse \*2 Each terminal mounted on a reference land

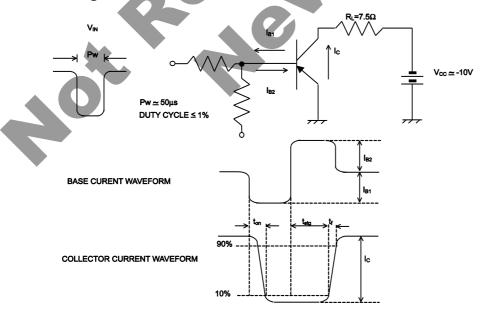
<sup>\*3</sup> Mounted on a ceramic board (40×40×.70mm)

### ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	$I_C = -1mA$	-80	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_C = -100 \mu A$	-80	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	$I_E = -100 \mu A$	-6	ı		V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -80V$	ı	-	1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -4V$	-	-	-1	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *1	$I_{\rm C} = -1A, \ I_{\rm B} = -50 {\rm mA}$		-0.20	-0.40	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -3V, I_{C} = -100 \text{mA}$	120	-	390	-
Transition frequency	f <sub>T</sub>	$V_{CE} = -10V, I_{E} = 500\text{mA}$ f=100MH <sub>Z</sub>	_	280	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz		32	-	pF
Turn-on time	t <sub>on</sub> *2	I <sub>C</sub> = −1.3A	Ĵ	50	ı	ns
Storage time	t <sub>stg</sub> *2	I <sub>B1</sub> = -130mA I <sub>B2</sub> =130mA	-	400	-	ns
Fall time	t <sub>f</sub> *2	V <sub>CC</sub> <sup>≃</sup> −10V	-	40	-	ns

<sup>\*1</sup> Pulsed

# •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

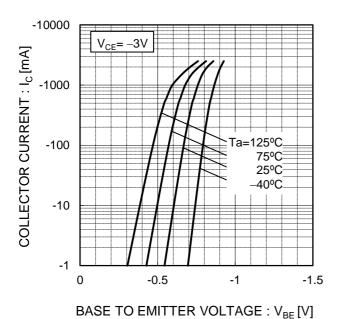
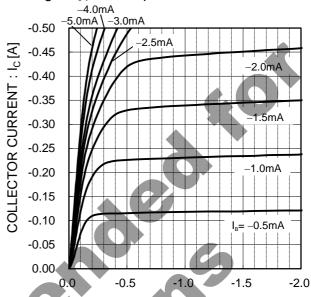


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V<sub>CE</sub>[V]

Fig.3 DC Current Gain vs. Collector Current(I)

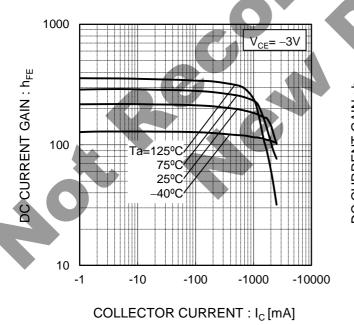
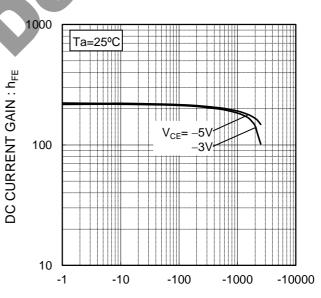


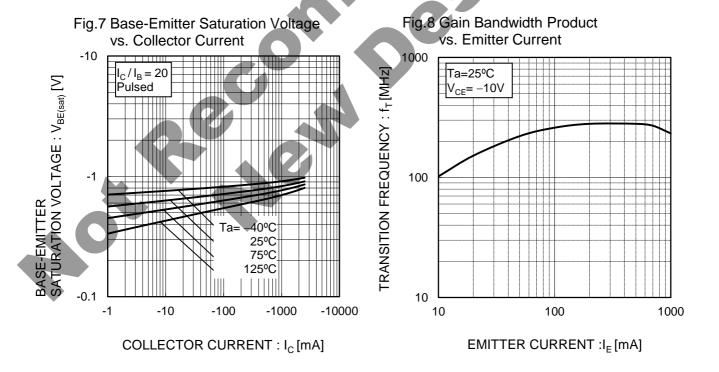
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I<sub>C</sub> [mA]

### ●Electrical characteristic curves(Ta = 25°C)

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) -1  $I_{\rm C}/I_{\rm B} = 20$ Ta=25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V<sub>CE(sat)</sub> [V] SATURATION VOLTAGE: V<sub>CE(sat)</sub> [V] COLLECTOR-EMITTER -0.1 -0.1  $I_{\rm C}/I_{\rm B} = 50^{\circ}$ 20 Ta=125°C 10 75°C 25°C -40°C -0.01 -1 -100 -1000 -10000 -100 -1000 -10000 COLLECTOR CURRENT : I<sub>C</sub> [mA] COLLECTOR CURRENT : I<sub>C</sub> [mA]



### ●Electrical characteristic curves(Ta = 25°C)

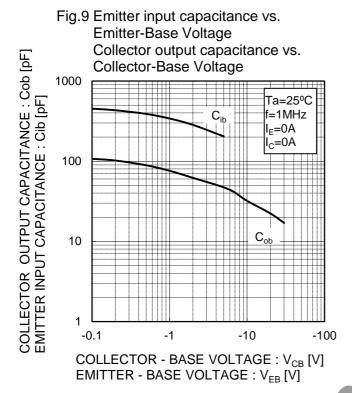
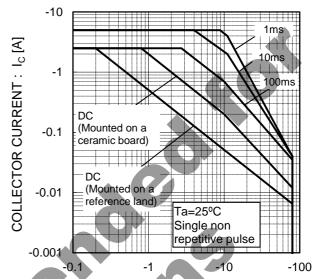
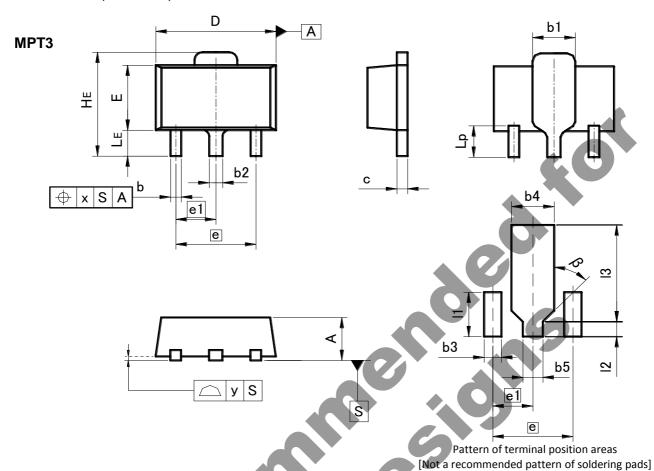


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V<sub>CE</sub> [V]

## ● **Dimensions** (Unit: mm)



		·			
DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
G	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.	50	0.0	59	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
X	_	0.15	_	0.006	
У	-	0.10	-	0.004	

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b3	_	0.65	I	0.026
b4	-	1.70	1	0.067
b5	_	0.75	-	0.030
l1		1.71	I	0.067
12	_	0.58	I	0.023
13	_	3.72	_	0.146
β	45°		45°	

Dimension in mm / inches

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